NSN 5961-01-149-1985

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-149-1985 **Inclosure Material:** Plastic **Overall Length:** 0.645 inches **Overall Height:** 0.135 inches **Overall Width:** 0.505 inches **End Application:** Fbm support 13604 **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to emitter voltage/static/base open and 60.0 collector to base voltage, dc and 5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 15.00 amperes source cutoff current **Power Rating Per Characteristic:** 90.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No